



20V P-Channel Enhancement Mode MOSFET- ESD Protected

Voltage

-20 V

Current

-4.0A

Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-4.0A<60m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-3.3A<70m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-2.5V$, $I_{D}@-2.0A<96m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-1.8V$, $I_D@-0.5A<180m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

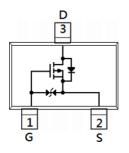
• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams







Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-20	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 8		
Continuous Drain Current(Note 4)		ID	-4	A	
Pulsed Drain Current(Note 1)		I _{DM}	-16		
Power Dissipation	T _a =25°C	P _D	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient ^(Note 3,4)		Reja	100	°C/W	





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	.,
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-0.5	-0.77	-1.2	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4A	-	50	60	mΩ
		V _{GS} =-4.5V, I _D =-3.3A	-	58	70	
		V _{GS} =-2.5V, I _D =-2A	-	80	96	
		V _{GS} =-1.8V, I _D =-0.5A	-	140	180	
Zero Gate Voltage Drain Current	I _{DSS} V _{DS} =-20V, V _{GS} =0	V _{DS} =-20V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	-	<u>+</u> 10	
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	V _{DS} =-10V, I _D =-4.0A, V _{GS} =-4.5V ^(Note 1,2)	-	6.9	-	nC
Gate-Source Charge	Q_{gs}		-	1.5	-	
Gate-Drain Charge	Q_{gd}		-	1.9	-	
Input Capacitance	Ciss	V _{DS} =-10V, V _{GS} =0V, f=1MHZ	-	602	-	pF
Output Capacitance	Coss		-	70	-	
Reverse Transfer Capacitance	Crss		-	47	-	
Turn-On Delay Time	td _(on)	V_{DD} =-10V, I_{D} =-4.0A, V_{GS} =-4.5V, R_{G} =3 $\Omega^{(Note 1,2)}$	-	8.8	-	ns
Turn-On Rise Time	tr		-	66	-	
Turn-Off Delay Time	td _(off)		-	29	-	
Turn-Off Fall Time	tf		-	14	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	-1.5	А
Diode Forward Voltage	V _{SD}	Is=-1A, V _{GS} =0V	-	-0.79	-1	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

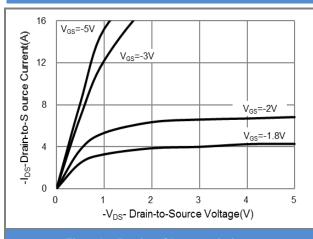


Fig.1 On-Region Characteristics

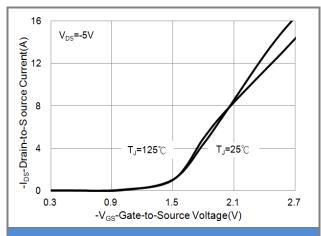


Fig.2 Transfer Characteristics

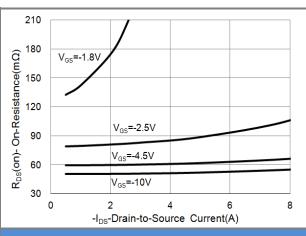


Fig.3 On-Resistance vs. Drain Current

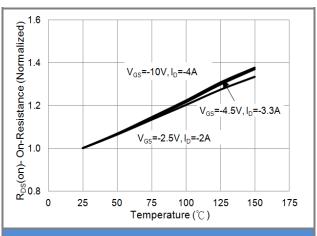


Fig.4 On-Resistance vs. Junction temperature

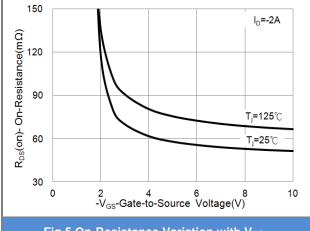
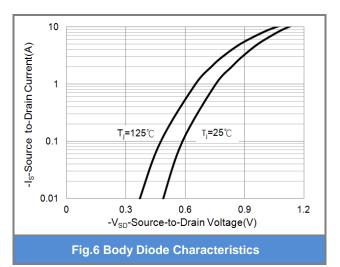


Fig.5 On-Resistance Variation with V_{GS}







TYPICAL CHARACTERISTIC CURVES

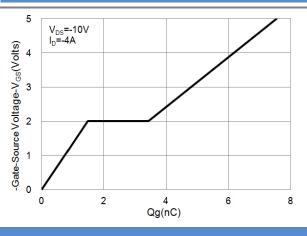


Fig.7 Gate-Charge Characteristics

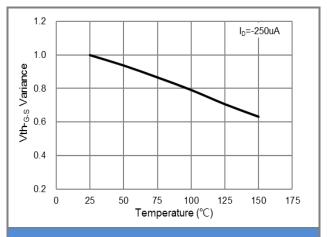


Fig.8 Threshold Voltage Variation with Temperature

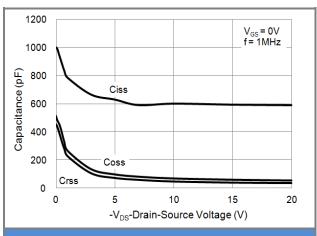


Fig.9 Capacitance vs. Drain-Source Voltage

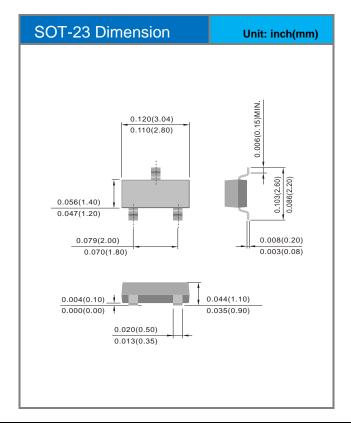


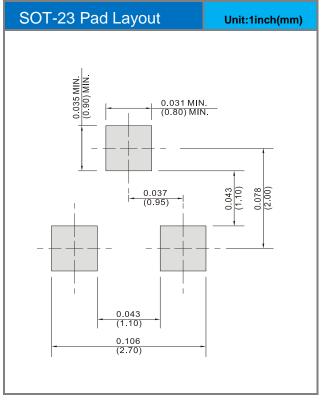


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJA3419-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A19	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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